

SILICON TRANSISTOR 2SA1871

PNP SILICON TRIPLE DIFFUSED TRANSISTOR FOR HIGH-SPEED HIGH-VOLTAGE SWITCHING

The 2SA1871 is a transistor developed for high-speed high-voltage switching and is ideal for use in switching elements such as switching regulators and DC/DC converters.

FEATURES

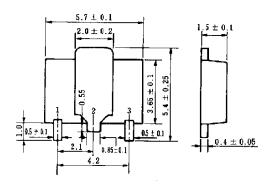
- New package with dimensions in between those of small signal and power signal package
- · High voltage
- · Fast switching speed
- · Complementary transistor with 2SC4942

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1: Emitter
- 2: Collector
- 3: Base

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vcво		-600	V
Collector to emitter voltage	VCEO		-600	V
Emitter to base voltage	VEBO		-7.0	V
Collector current (DC)	Ic(DC)		-1.0	Α
Collector current (pulse)	IC(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 %	-2.0	Α
Total power dissipation	Рт	$7.5~\text{cm}^2\times0.7~\text{mm}$ ceramic board used	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	T _{stg}		−55 to +150	°C

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



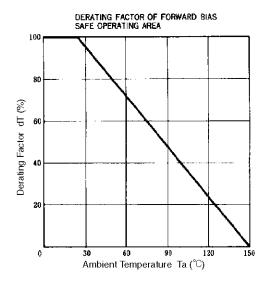
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

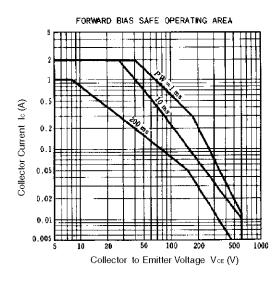
Parameter	Symbol	Conditions MIN.		TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = -600 V, I _E = 0			-10	μΑ
Emitter cutoff current	ІЕВО	V _{EB} = -7.0 V, I _C = 0			-10	μΑ
DC current gain	h _{FE1}	Vce = -5.0 V, Ic = -0.1 A 30		60	120	-
DC current gain	h _{FE2}	VcE = -5.0 V, Ic = -0.5 A	5	20		-
Collector saturation voltage	V _{CE(sat)}	$I_{C} = -300 \text{ mA}, I_{B} = -60 \text{ mA}$		-0.3	-1.0	V
Base saturation voltage	V _{BE(sat)}	$I_{C} = -300 \text{ mA}, I_{B} = -60 \text{ mA}$		-0.85	-1.2	V
Gain bandwidth product	f⊤	VcE = -10 V, IE = 50 mA		30		MHz
Output capacitance	Cob	V _{CB} = −10 V, I _E = 0, f = 1.0 MHz		40		pF
Turn-on time	ton	Ic = -0.5 A, $Vcc = -250 V$		0.1	0.5	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.1 \text{ A},$ $R_L = 500 \Omega,$		3.5	5.0	μs
Fall time	tf	1 IL — 300 \$2,		0.1	0.5	μs

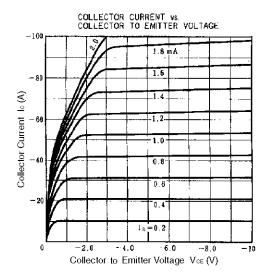
hfe CLASSIFICATION

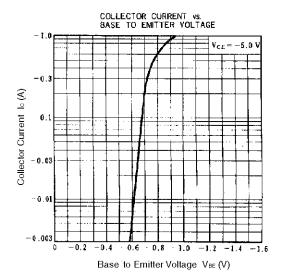
Marking	GA1	GA2	GA3
h _{FE1}	30 to 60	40 to 80	60 to 120

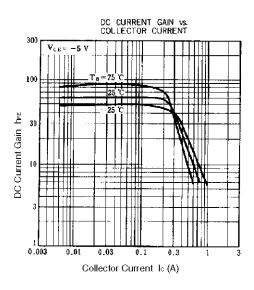
TYPICAL CHARACTERISTICS (Ta = 25°C)

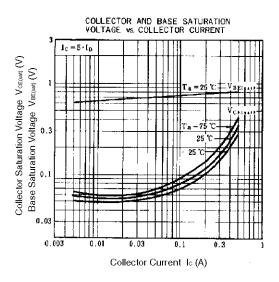


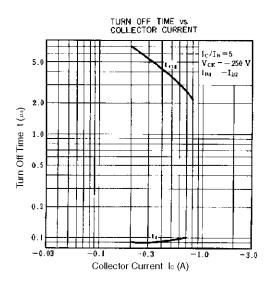


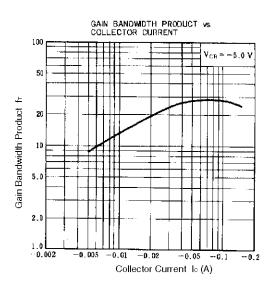






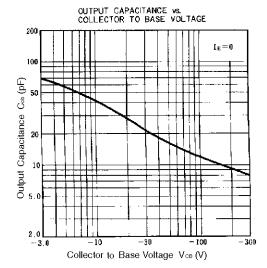






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